



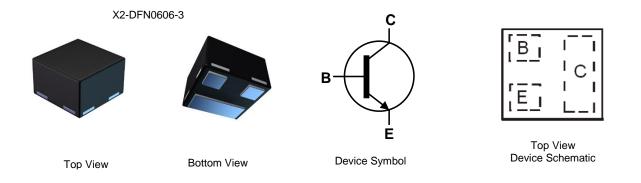
Features

- $BV_{CEO} > 40V$
- I_C = 200mA High Collector Current
- P_D = 925mW Power Dissipation
- 0.36mm² Package Footprint, 40% Smaller than DFN1006
- 0.4mm Height Package Minimizing Off-Board Profile
- Complementary PNP Type MMBT3906FZ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

40V NPN SMALL SIGNAL TRANSISTOR IN DFN0606

Mechanical Data

- Case: X2-DFN0606-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish --- NiPdAu, Solderable per MIL-STD-202, Method 208 e4
- Weight: 0.0008 grams (Approximate)



Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBT3904FZ-7B	1N	7	8mm	10,000
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.				

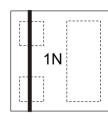
No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



1N = Product Type Marking Code

Top View Bar Denotes Base and Emitter Side



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current	Ic	200	mA
Peak Pulse Collector Current	I _{CM}	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D	270	mW	
	(Note 6)	(Note 6)		TIVV	
Thermal Desistance, Junction to Ambient	(Note 5)		465	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ extsf{ heta}JA}$	135	C/W	
Thermal Resistance, Junction to Lead (Note 7)		R _{θJL}	135	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

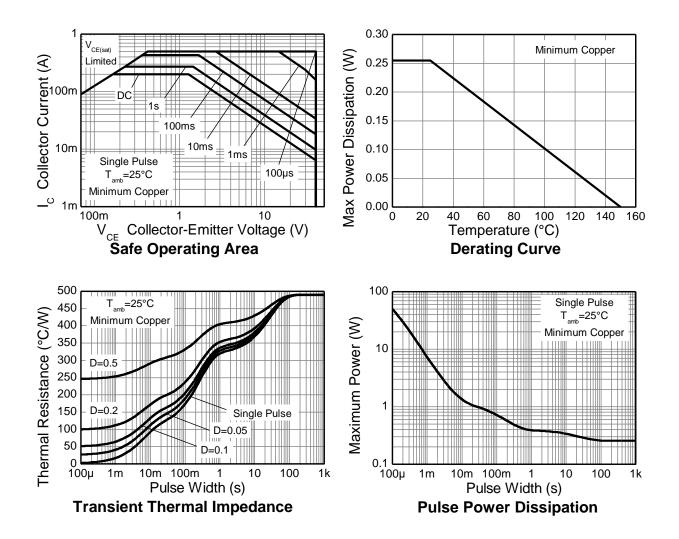
ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	200	V	В

Notes: 5. For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured So the device mounted on minimum recommended pad layout 102 copper that is on a single-sided 1.5mm PR4 PCB, device is if under still air conditions whilst operating in steady state condition. The entire exposed collector pad is attached to the heatsink.
Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.
Thermal resistance from junction to solder-point (on the exposed collector pad).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





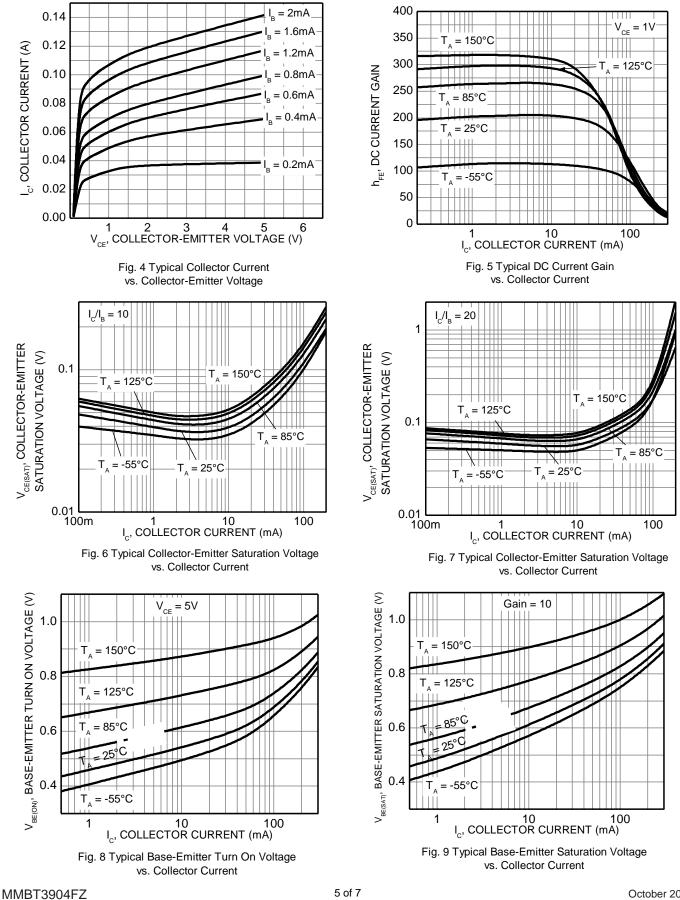
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS			1	T	1
Collector-Base Breakdown Voltage	ВV _{CBO}	60	—	V	$I_{\rm C} = 100 \mu {\rm A}, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	40		V	$I_{\rm C} = 10.0 {\rm mA}, \ I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	—	V	$I_E = 100 \mu A, I_C = 0$
Collector Cutoff Current	ICEX	—	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
Base Cutoff Current	I _{BL}	_	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
ON CHARACTERISTICS (Note 9)					
DC Current Gain	h _{FE}	40 70 100 60 30	— 300 —	_	$\begin{split} I_{C} &= 100 \mu A, \ V_{CE} &= 1.0 V \\ I_{C} &= 1.0 m A, \ V_{CE} &= 1.0 V \\ I_{C} &= 10 m A, \ V_{CE} &= 1.0 V \\ I_{C} &= 50 m A, \ V_{CE} &= 1.0 V \\ I_{C} &= 100 m A, \ V_{CE} &= 1.0 V \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	0.20 0.30	V	$I_C = 10mA$, $I_B = 1.0mA$ $I_C = 50mA$, $I_B = 5.0mA$
Base-Emitter Saturation Voltage	V _{BE(sat)}	0.65	0.85 0.95	V	$I_{C} = 10mA, I_{B} = 1.0mA$ $I_{C} = 50mA, I_{B} = 5.0mA$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	_	4.0	pF	V _{CB} = 5.0V, f = 1.0MHz, I _E = 0
Input Capacitance	C _{ibo}	_	9.5	pF	V _{EB} = 0.5V, f = 1.0MHz, I _C = 0
Current Gain-Bandwidth Product	fT	300	_	MHz	$V_{CE} = 20V, I_C = 10mA, f = 100MHz$
SWITCHING CHARACTERISTICS	·		•	•	÷
Delay Time	t _d	_	35	ns	$V_{CC} = 3.0V, I_{C} = 10mA,$
Rise Time	tr		35	ns	$V_{BE(off)} = -0.5V, I_{B1} = 1.0mA$
Storage Time	ts		200	ns	$V_{CC} = 3.0V, I_C = 10mA,$
Fall Time	t _f	_	50	ns	$I_{B1} = I_{B2} = 1.0 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

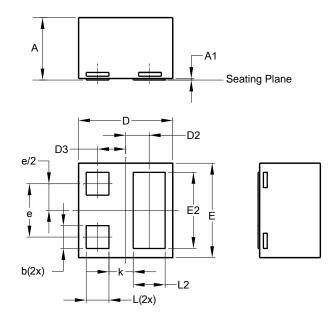


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Package Outline Dimensions

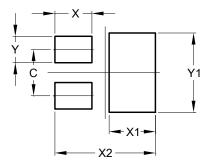
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	X2-DFN0606-3				
Dim	Min	Max	Тур		
Α	0.36	0.42	0.39		
A1	0	0.05	0.02		
b	0.10	0.20	0.15		
D	0.57 0.67 0.62				
D2	0.155 BSC				
D3	0	.185 BS	С		
ш	0.57	0.67	0.62		
E2	0.40	0.60	0.50		
e	0.35 BSC				
k	0.16 REF				
L	0.09	0.21	0.15		
L2	0.11	0.31	0.21		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	0.350		
Х	0.280		
X1	0.350		
X2	0.760		
Y	0.200		
Y1	0.600		



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